

1A1~1A7

MINIATURE PLASTIC SILICON RECTIFIER

VOLTAGE 50 to 1000 Volts **CURRENT** 1.0 Amperes

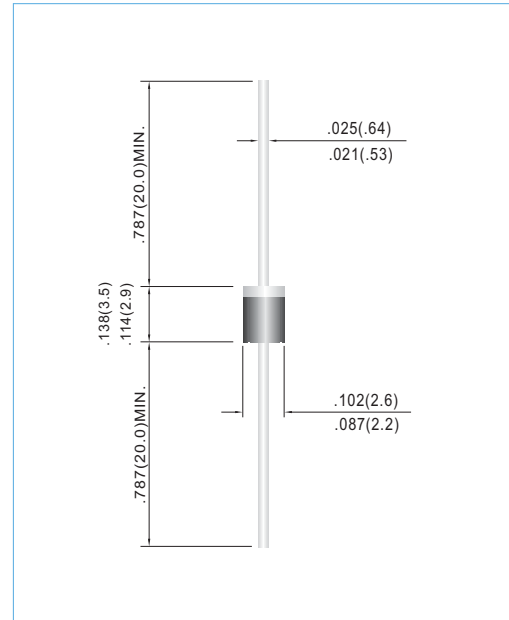
R-1 Unit: inch(mm)

FEATURES

- High reliability.
- Low leakage.
- Low forward voltage drop.
- High current capability.
- Exceeds environmental standards of MIL-S-19500 / 228
- In compliance with EU RoHS 2002/95/EC directives

MECHANICAL DATA

- Case: Molded plastic, R-1
- Epoxy: UL 94V-O rate flame retardant.
- Lead: MIL-STD-750 method 2026
- Mounting Position: Any
- Weight: 0.0064 ounce, 0.181 gram



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified. Resistive or inductive load, 60Hz.

PARAMETER	SYMBOL	1A1	1A2	1A3	1A4	1A5	1A6	1A7	UNITS
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	V_{RMS}	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	V_{DC}	50	100	200	400	600	800	1000	V
Maximum Average Forward Current .375"(9.5mm) lead length at $T_A=50^{\circ}C$	$I_{F(AV)}$	1.0							A
Peak Forward Surge Current : 8.3ms single half sine-wave superimposed on rated load(JEDEC method)	I_{FSM}	30							A
Maximum Forward Voltage at 1.0A	V_F	1.1							V
Maximum DC Reverse Current at $T_J=25^{\circ}C$ Rated DC Blocking Voltage $T_J=100^{\circ}C$	I_R	5.0 500							μA
Typical Junction capacitance (Note 1)	C_J	15							pF
Typical Thermal Resistance	$R_{\theta JA}$	60							$^{\circ}C / W$
Operating Junction and Storage Temperature Range	T_J, T_{STG}	-55 to +150							$^{\circ}C$

NOTES:

1. Measured at 1MHz and applied reverse voltage of 4.0 volts.

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RATING AND CHARACTERISTIC CURVES

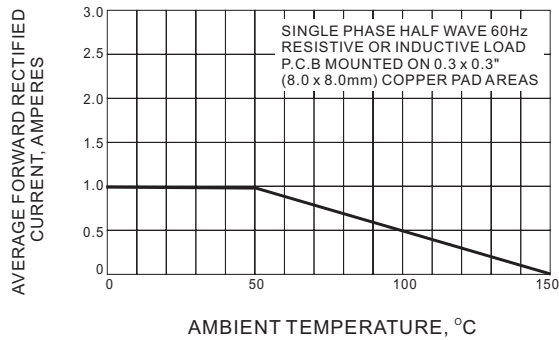


Fig.1 FORWARD CURRENT DERATING CURVE

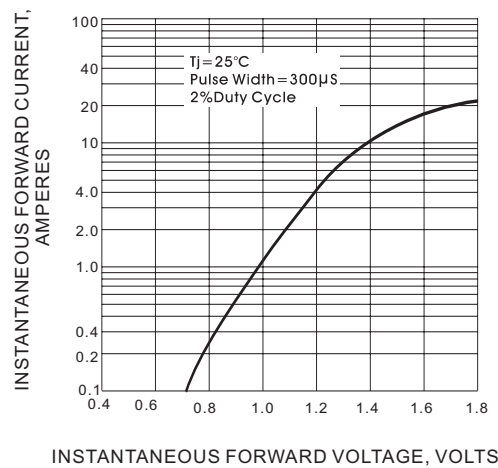


Fig.2-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

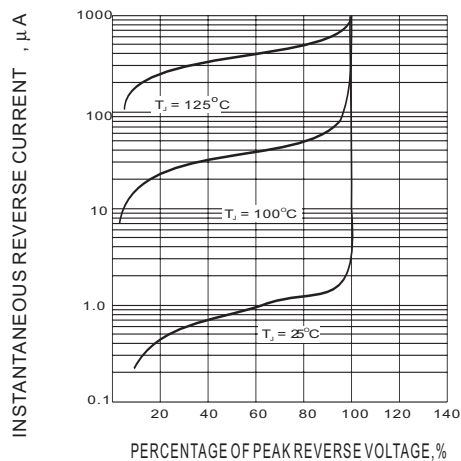


Fig.3-TYPICAL REVERSE CHARACTERISTIC

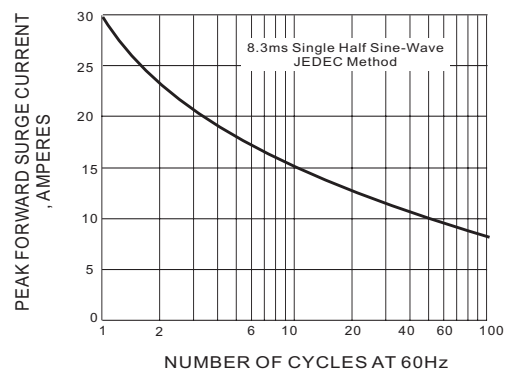


Fig.4-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

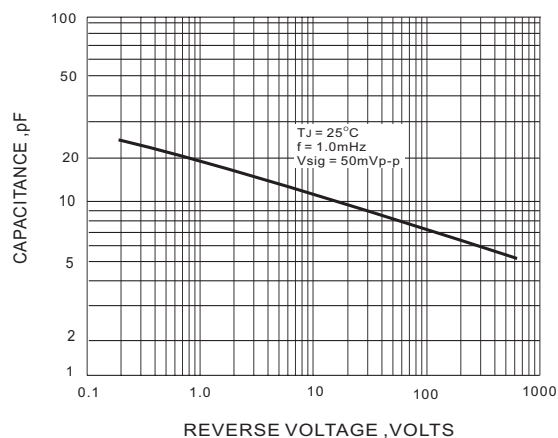


Fig.5 TYPICAL JUNCTION CAPACITANCE